ABSTRACT OF THE DISCLOSURE

5

10

15

20

There is provided an active matrix substrate which enables to shorten a fabrication process of a pixel electrode, improve exposure precision by self alignment, and prevent leakage failures between pixel electrodes. active matrix substrate has TFTs disposed in the shape of a matrix. On a light permeable substrate, there are formed gate signal lines and capacity lines. On a gate insulating film on the lines, there are formed in sequence semiconductor laver, source electrode and a a electrode separated right and left by a channel protection Thus, the TFTs are fabricated. Then, the entire substrate is covered with an interlayer insulating film. On top of the interlayer insulating film, there are formed pixel electrodes, which are connected to the TFTs through contact holes piercing through the interlayer insulating The pixel electrodes are formed by applying on the interlayer insulating film a photosensitive transparent resin such as negative acrylic polymerized resin containing ATO or ZnO as transparent conductive particles, ITO, performing exposure from the back side of the substrate, and conducting development.